

/ Descriptions

SOT-323 PNP Silicon PNP transistor in a SOT-323 Plastic Package.

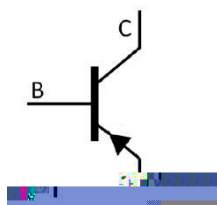
/ Features

P_C , h_{FE} , 9014W
Hig P_C and I_C , excellent h_{FE} linearity, complementary pair with 9014W.

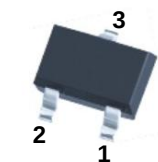
/ Applications

Low frequency, low noise pre-amplifier.

/ Equivalent Circuit



/ Pinning



PIN1 Emitter PIN 2 Base PIN 3 Collector

/ Marking

h_{FE} Classifications Symbol	A	B	C
h_{FE} Range	60 150	100 300	200 600
Marking	HM6A	HM6B	HM6C

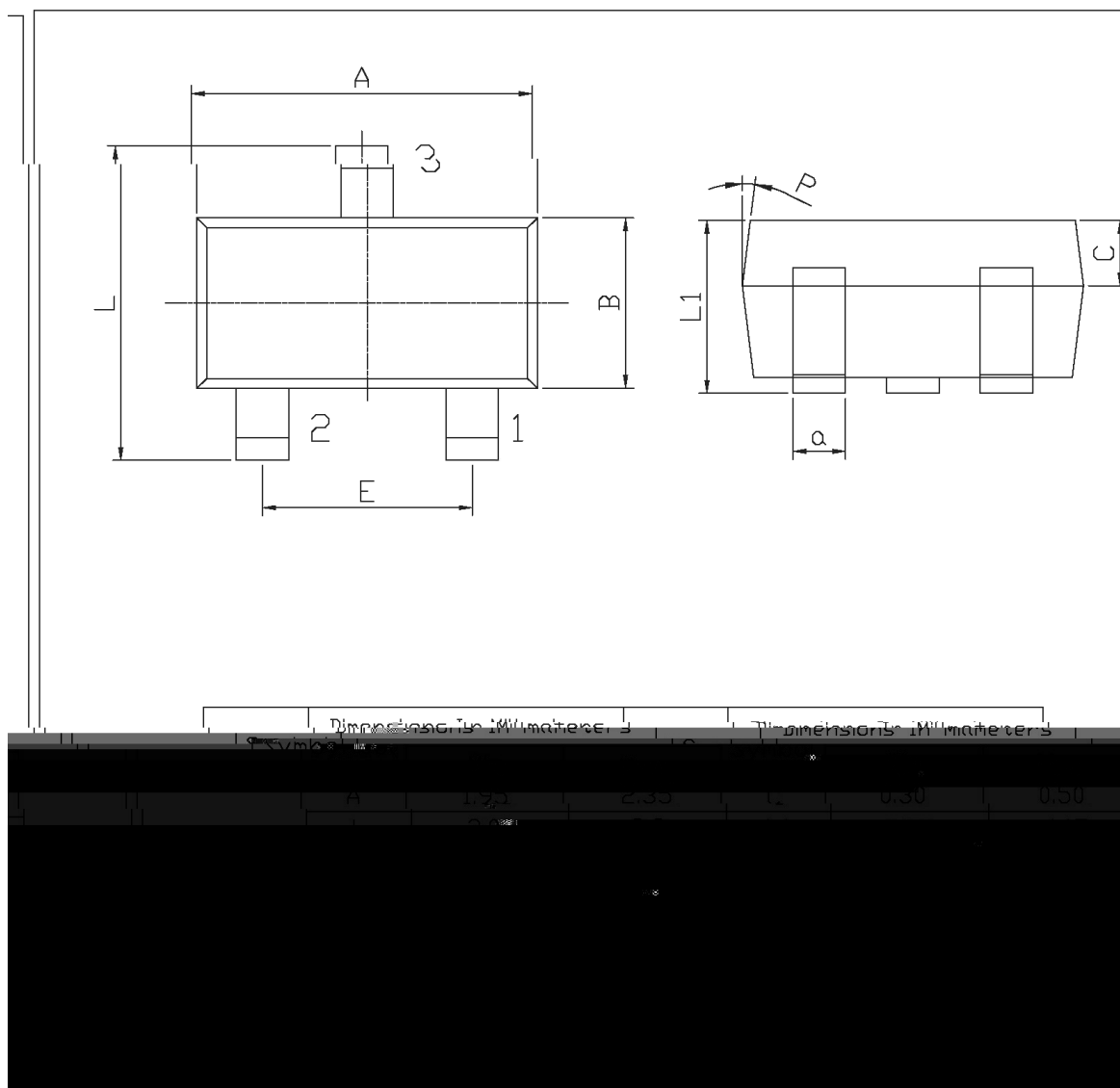
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-50	V
Collector to Emitter Voltage	V_{CEO}	-45	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-100	mA
Collector Power Dissipation	P_C	250	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

Parameter Symbol

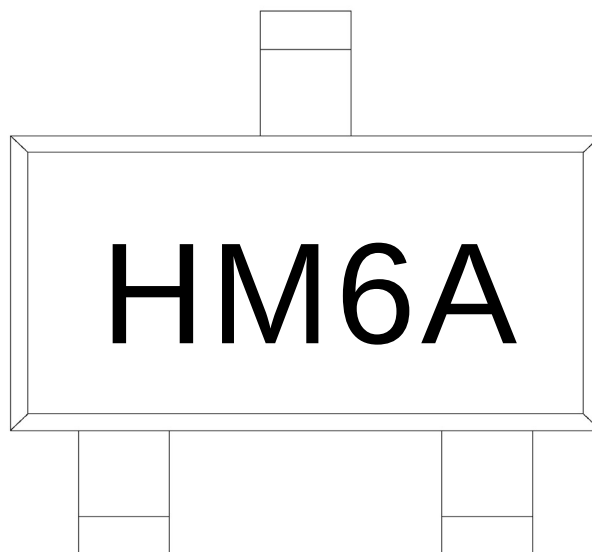
9015W
Rev.E Mar.-2016

9015-323

单位: mm



/ Marking Instructions



H

M6

A h_{FE}

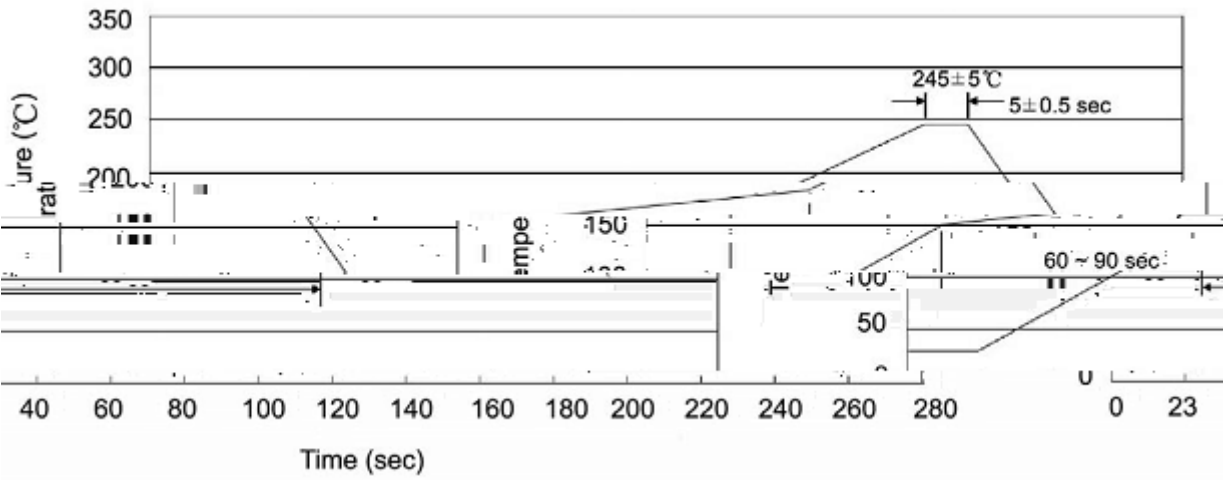
Note:

H: Company Code.

M6: Product Type.

A h_{FE} Classifications Symbol

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Note:

- 1

25 150

60 90sec;
- 2

245±5

5±0.5sec;
- 3

2 10 /sec.
- 1.Preheating:25~150 , Time:60~90sec.

2.Peak Temp.:245±5 , Duration:5±0.5sec.

3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

260±5 10±1 sec. Temp.:260±5 Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type	Units					Dimension (unit mm ³)		
	Units/Reel	Reels/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Reel	Inner Box	Outer Box
SOT-323	3,000	10	30,000	6	180,000	7 ×8	180×120×180	390×385×205

/ Notices